



# DIODE Type : 11ES4

## OUTLINE DRAWING

### FEATURES

- \* Miniature Size
- \* Low Forward Voltage drop
- \* Low Reverse Leakage Current
- \* High Surge Capability
- \* 26mm and 52mm Inside Tape Spacing Package Available



### Maximum Ratings

Approx Net Weight:0.17g

Rating	Symbol	11ES4		Unit	
Repetitive Peak Reverse Voltage	$V_{RRM}$	400		V	
Non-repetitive Peak Reverse Voltage	$V_{RSM}$	600		V	
Average Rectified Output Current	$I_O$	0.98	Ta=25°C *1	50Hz Half Sine Wave Resistive Load	A
		1.0	Ta=50°C *2		
RMS Forward Current	$I_{F(RMS)}$	1.57		A	
Surge Forward Current	$I_{FSM}$	45	50Hz Half Sine Wave, 1cycle, Non-repetitive	A	
Operating Junction Temperature Range	$T_{jw}$	- 40 to + 150		°C	
Storage Temperature Range	$T_{stg}$	- 40 to + 150		°C	

### Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit	
Peak Reverse Current	$I_{RM}$	$T_j = 25^\circ\text{C}, V_{RM} = V_{RRM}$	-	-	50	$\mu\text{A}$	
Peak Forward Voltage	$V_{FM}$	$T_j = 25^\circ\text{C}, I_{FM} = 1.0\text{A}$	-	-	1.0	V	
Thermal Resistance	$R_{th(j-a)}$	Junction to Ambient	*1	-	-	140	°C/W
			*2			110	

\*1: Without Fin or P.C. Board

\*2: P.C. Board Mounted (L=3mm, Print Land=5x5mm, Both Sides)



11ES4 OUTLINE DRAWING (Dimensions in mm)

